



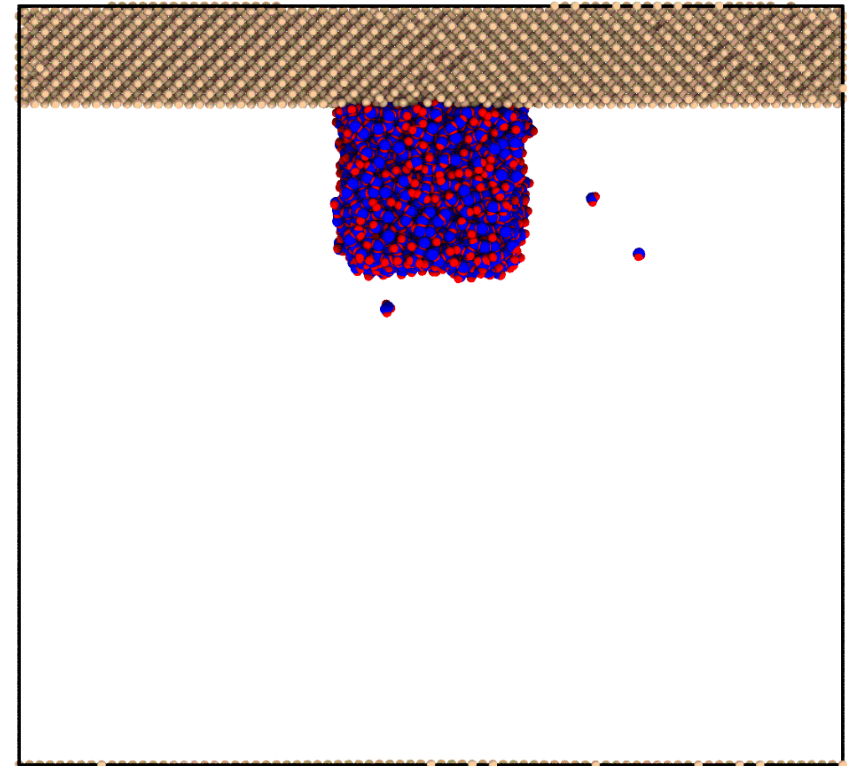
Atomistic simulations of thermal transport across the solid/liquid interface

Viktor Mandrolko, Mykola Isaiev

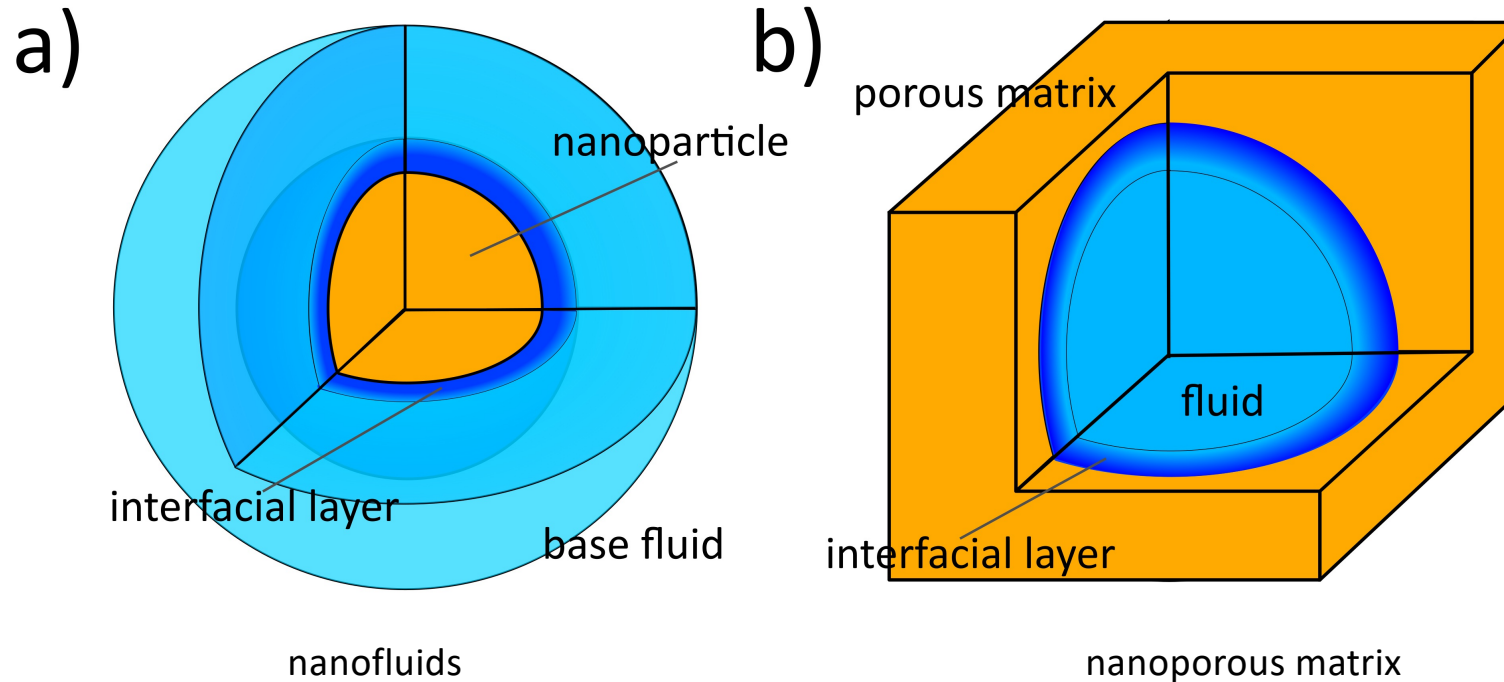
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Outline

1. Motivation
2. **Thermal transport across chemically functionalised interface**
 - 2.1. Wetting properties
 - 2.2. Work of adhesion
 - 2.3. Orientation of molecules
 - 2.3. Depletion length
3. **Thermal transport across a nanostructured interface**
 - 3.1. Contacting area
 - 3.2. Work of adhesion
4. Conclusions



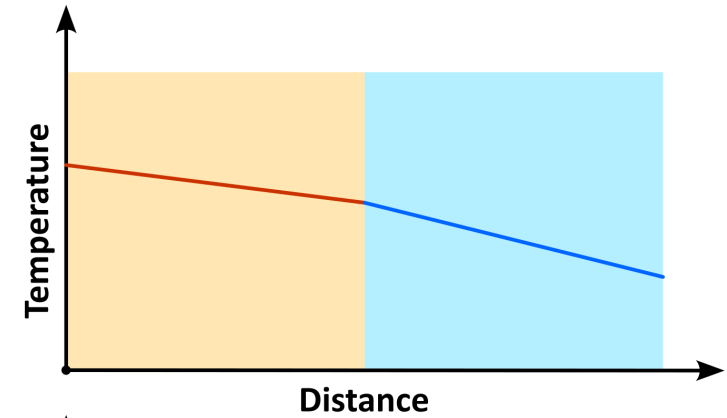
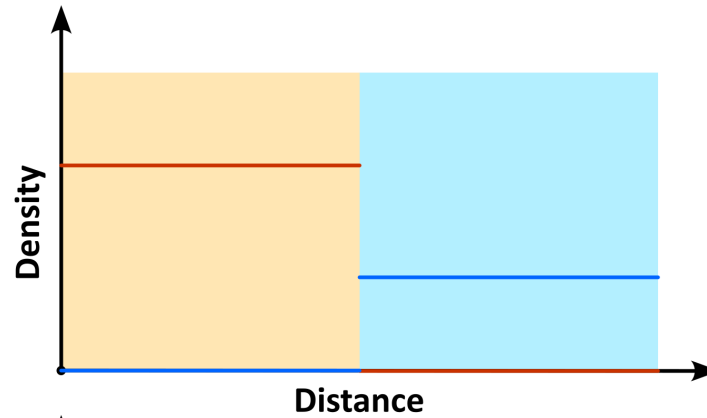
Motivation



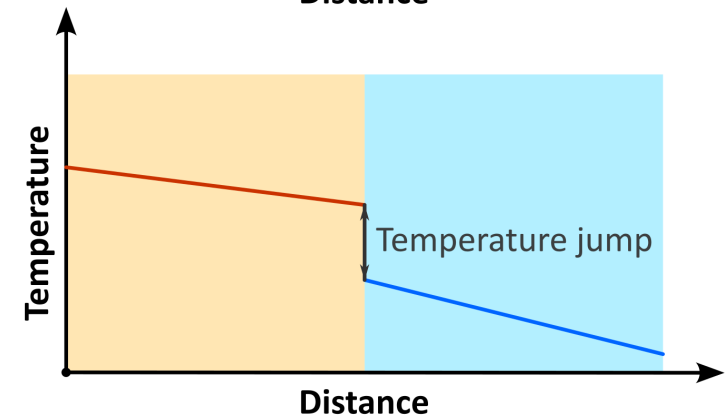
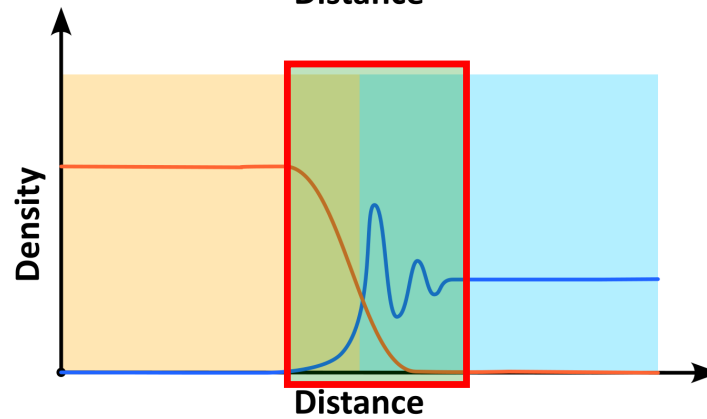
Thermal transport properties of the systems with a significant solid-liquid interface are sensitive to the interfacial thermal transport

Motivation

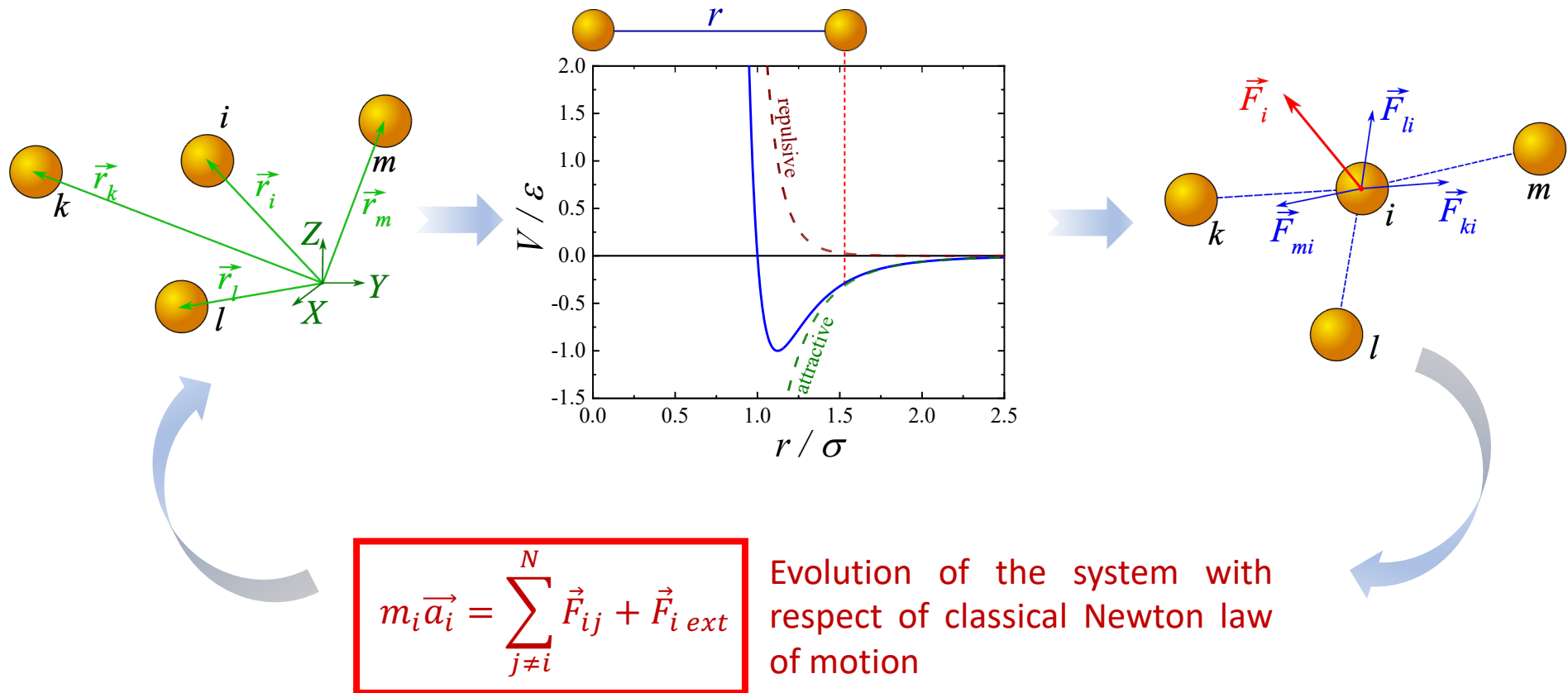
Macroscale



Nanoscale

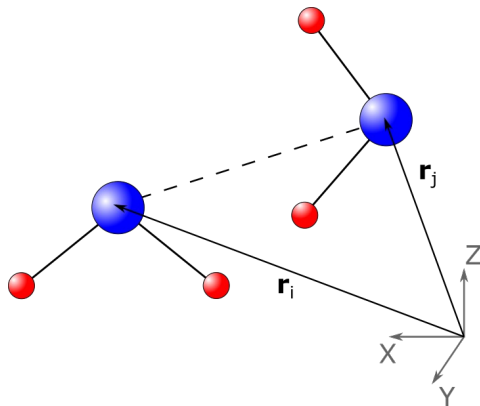


Molecular dynamics

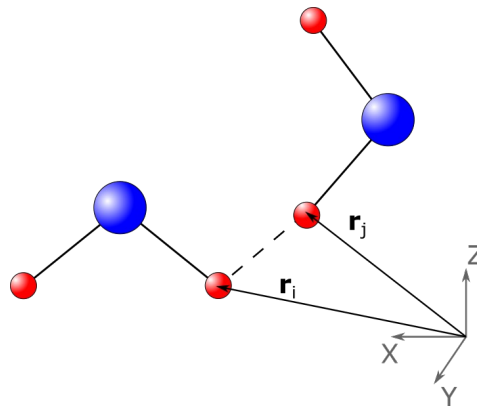


Water model

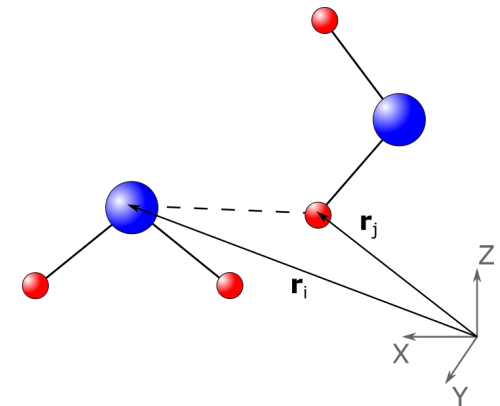
O-O



H-H



O-H

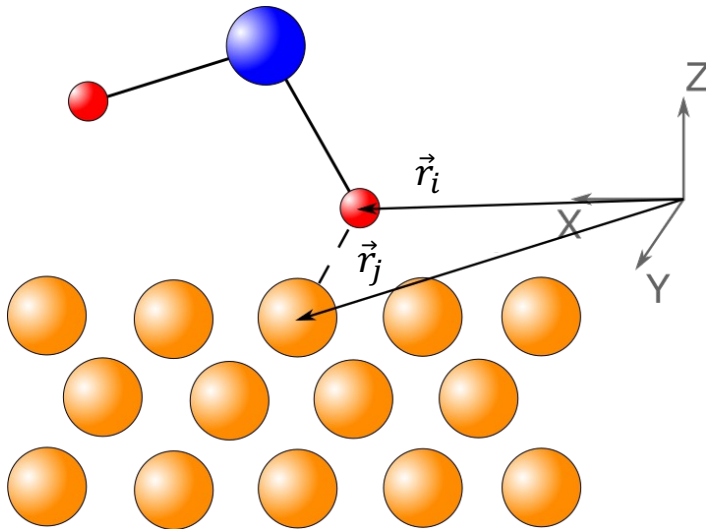


$$V_{O-O} = \frac{1}{4\pi\epsilon_1\epsilon_0} \frac{(q_o)^2}{|\vec{r}_i - \vec{r}_j|} + 4\epsilon \left(\left(\frac{\sigma}{|\vec{r}_i - \vec{r}_j|} \right)^{12} - \left(\frac{\sigma}{|\vec{r}_i - \vec{r}_j|} \right)^6 \right)$$

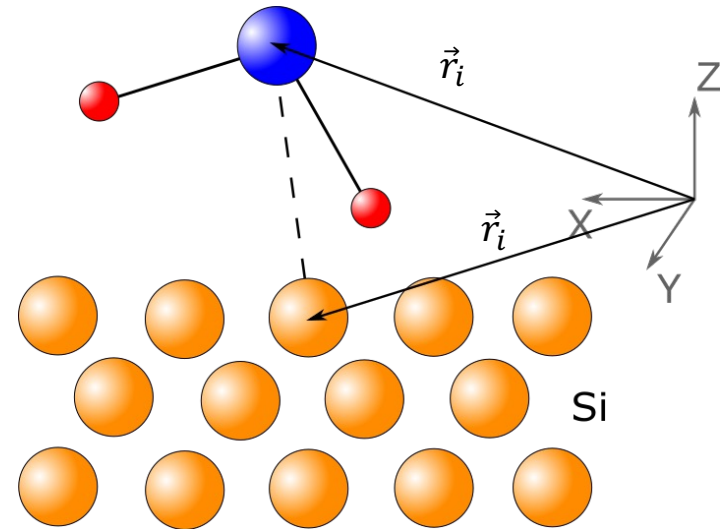
$$V_{H-H} = \frac{1}{4\pi\epsilon_1\epsilon_0} \frac{(q_H)^2}{|\vec{r}_i - \vec{r}_j|}$$

$$V_{O-H} = \frac{1}{4\pi\epsilon_1\epsilon_0} \frac{q_o q_H}{|\vec{r}_i - \vec{r}_j|}$$

Solid/liquid interactions

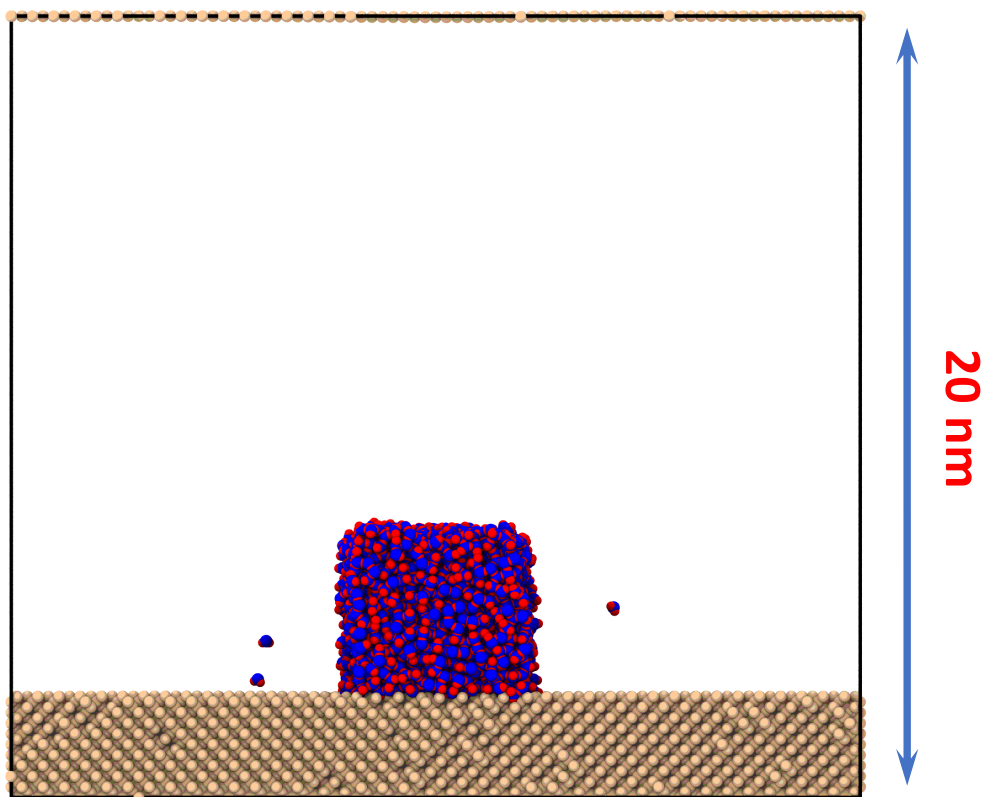


$$V_{O-Si} = 0$$



$$V_{O-Si} = 4\epsilon_{O-Si} \left(\left(\frac{\sigma_{O-Si}}{r} \right)^{12} - \left(\frac{\sigma_{O-Si}}{r} \right)^6 \right)$$

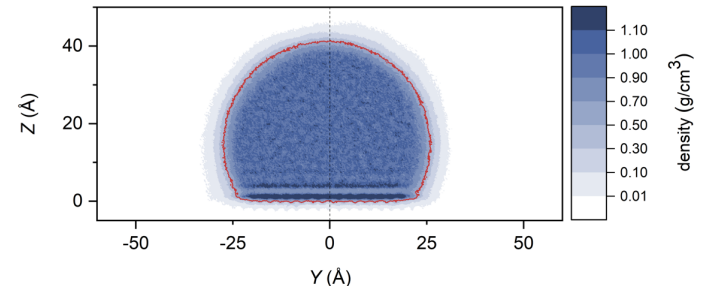
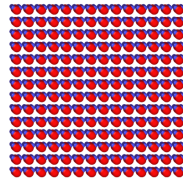
Wetting phenomena



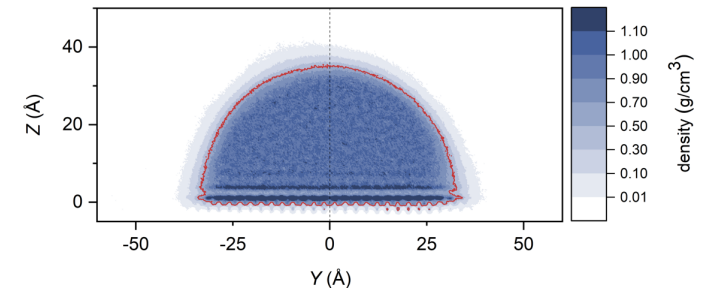
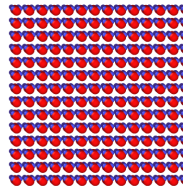
32 000 of silicon atoms
6820 water molecules

Wetting phenomena

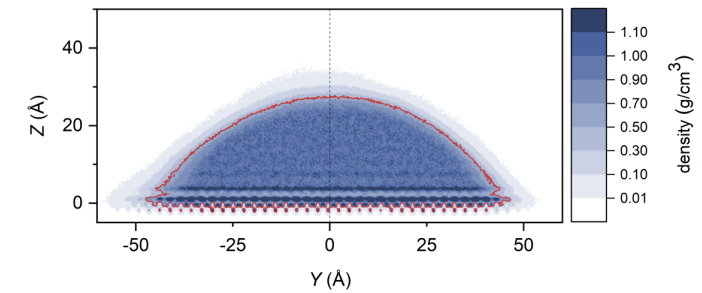
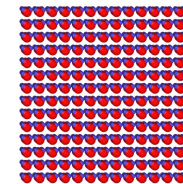
$\epsilon_{\text{O-Si}} = 10 \text{ meV}$



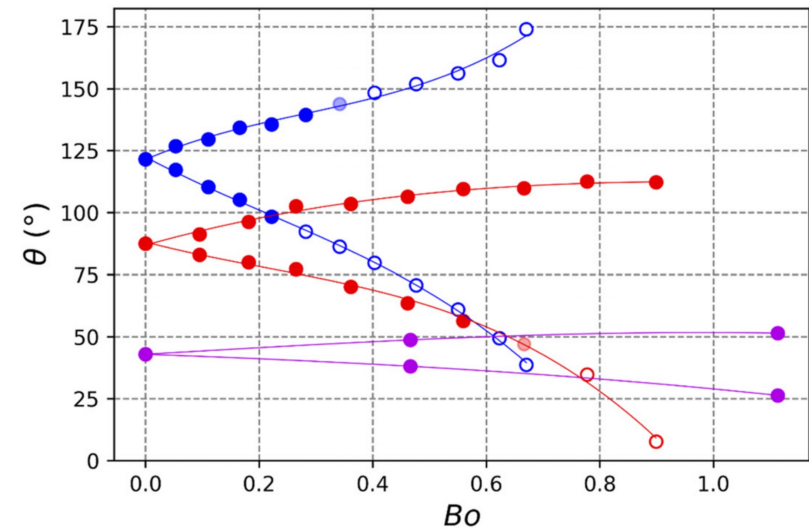
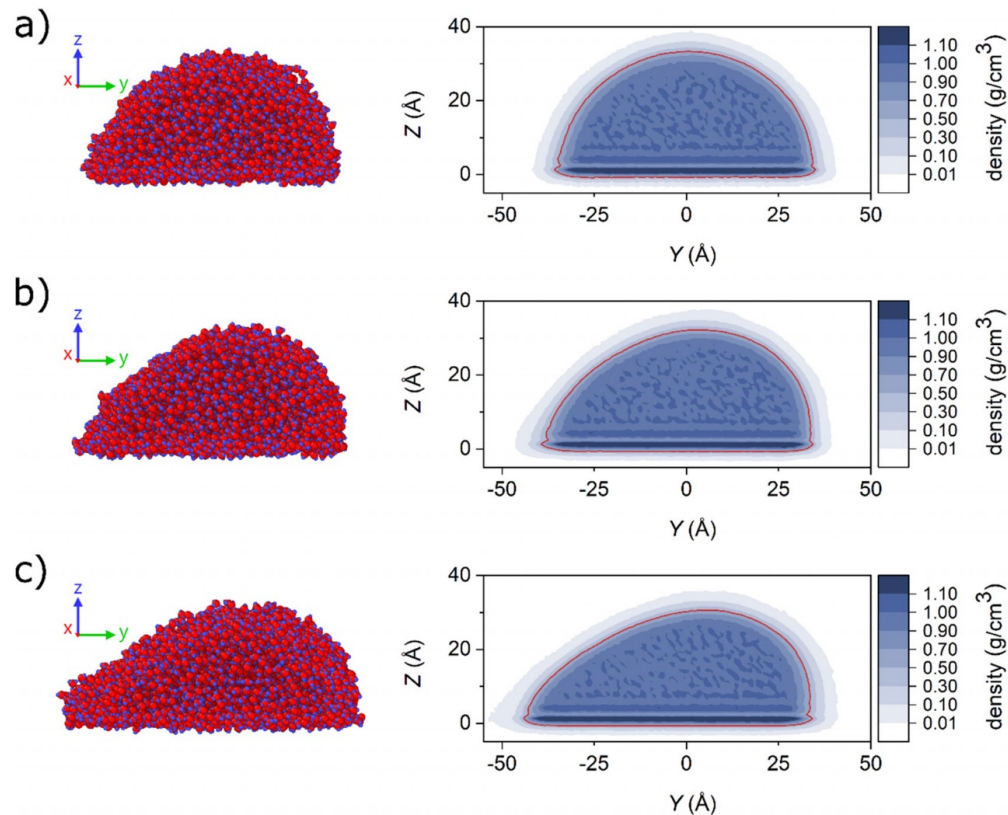
$\epsilon_{\text{O-Si}} = 15 \text{ meV}$



$\epsilon_{\text{O-Si}} = 21 \text{ meV}$

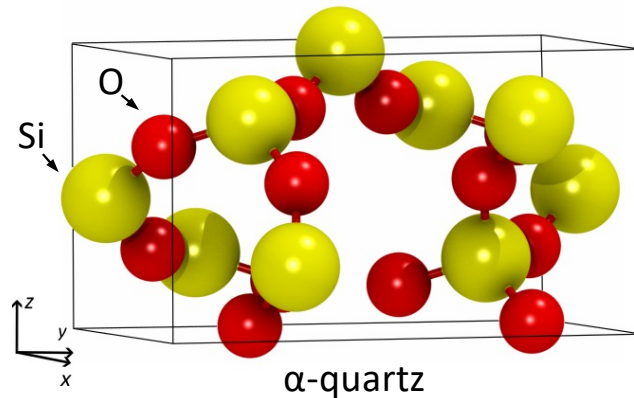
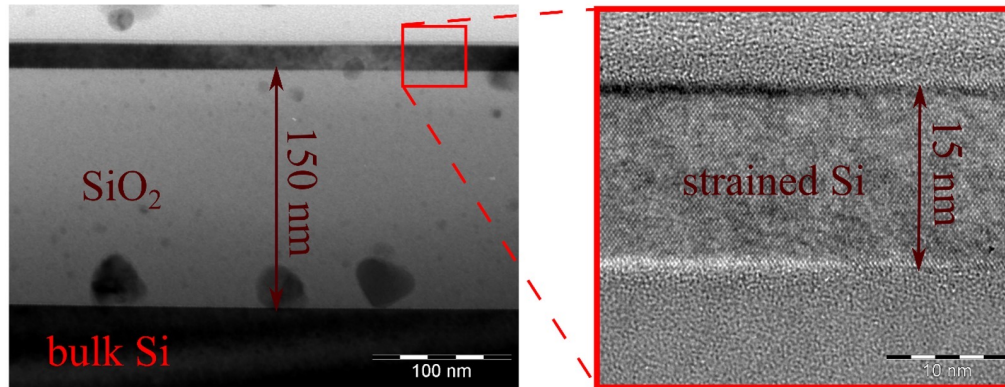


Wetting phenomena

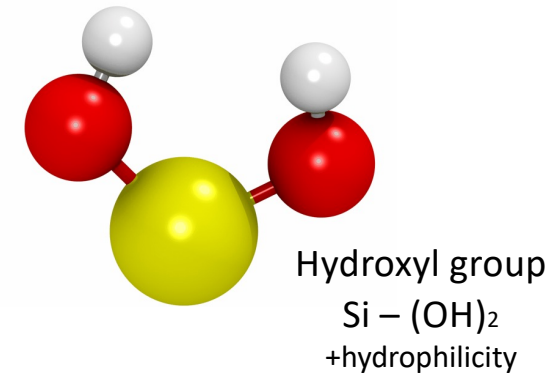
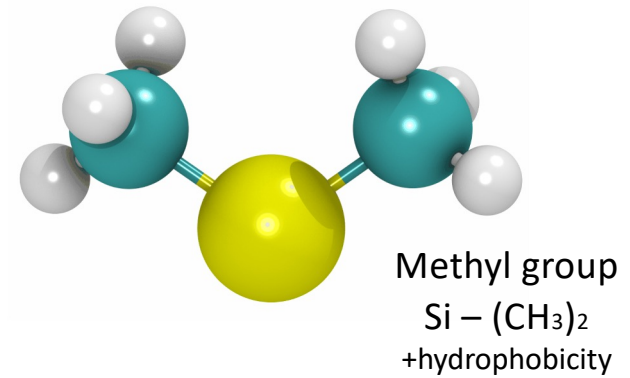


Mandrolko, V., ..., & Isaiev, M. (2024). Features of the contact angle hysteresis at the nanoscale: A molecular dynamics insight. *Physics of Fluids*, 36(5), 052012.

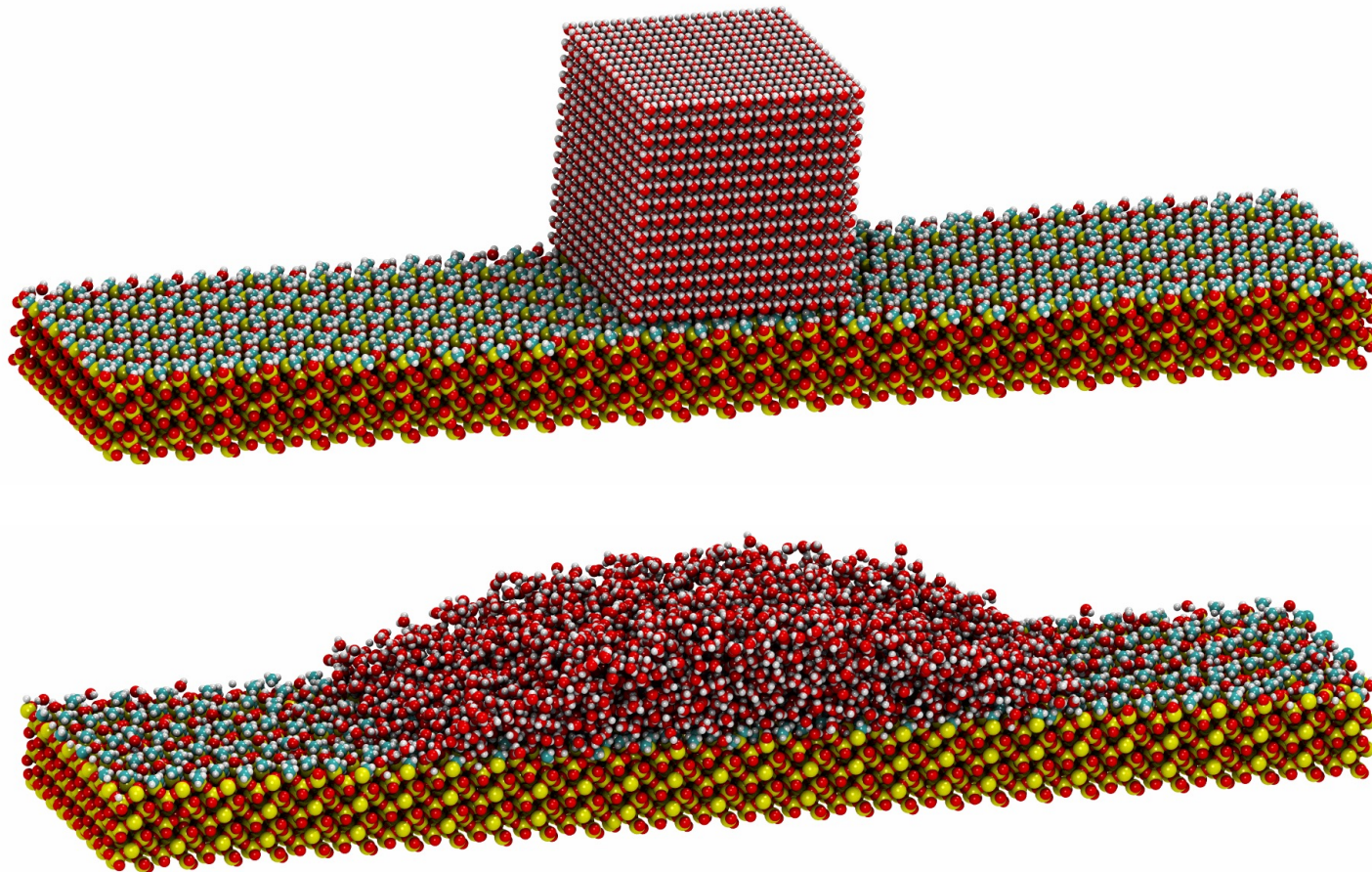
More complex interface



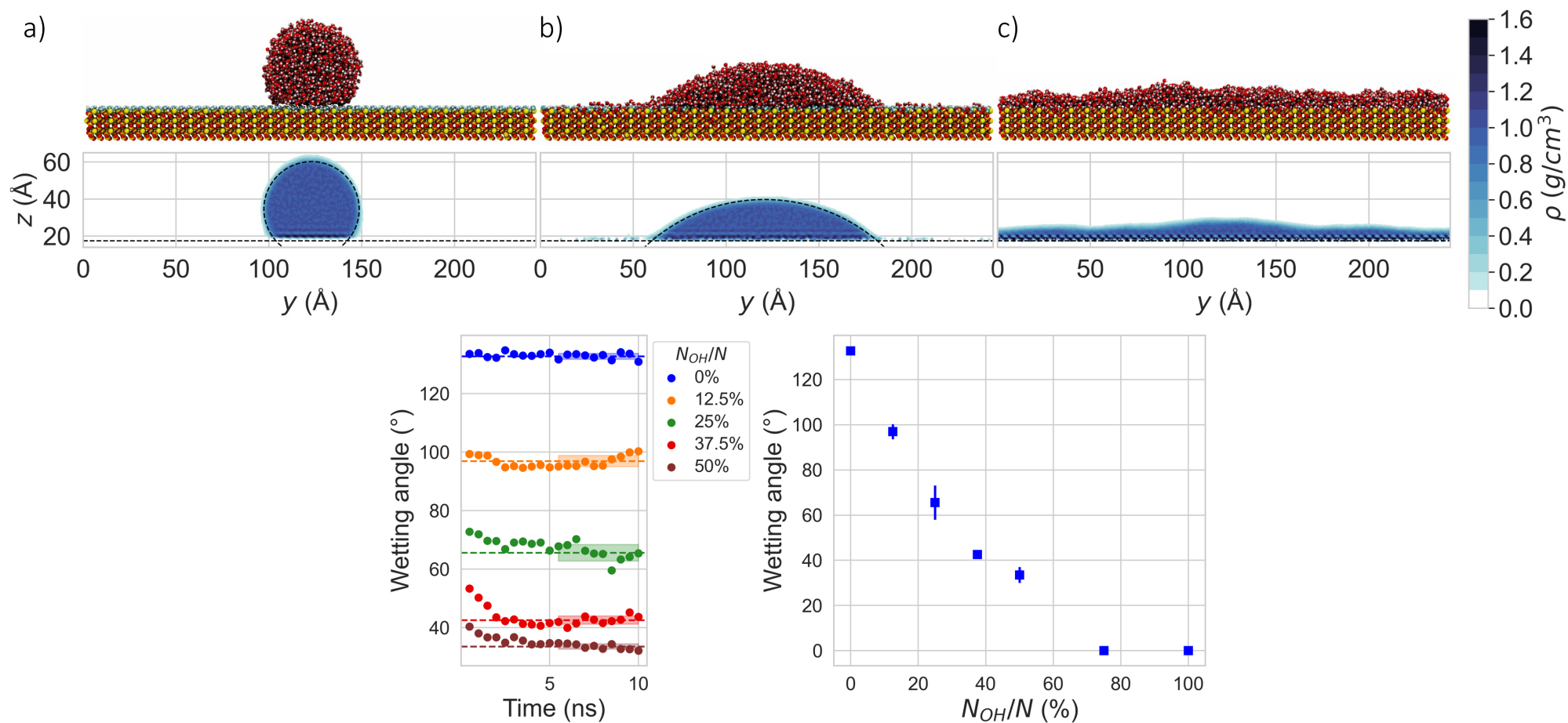
Functionalization



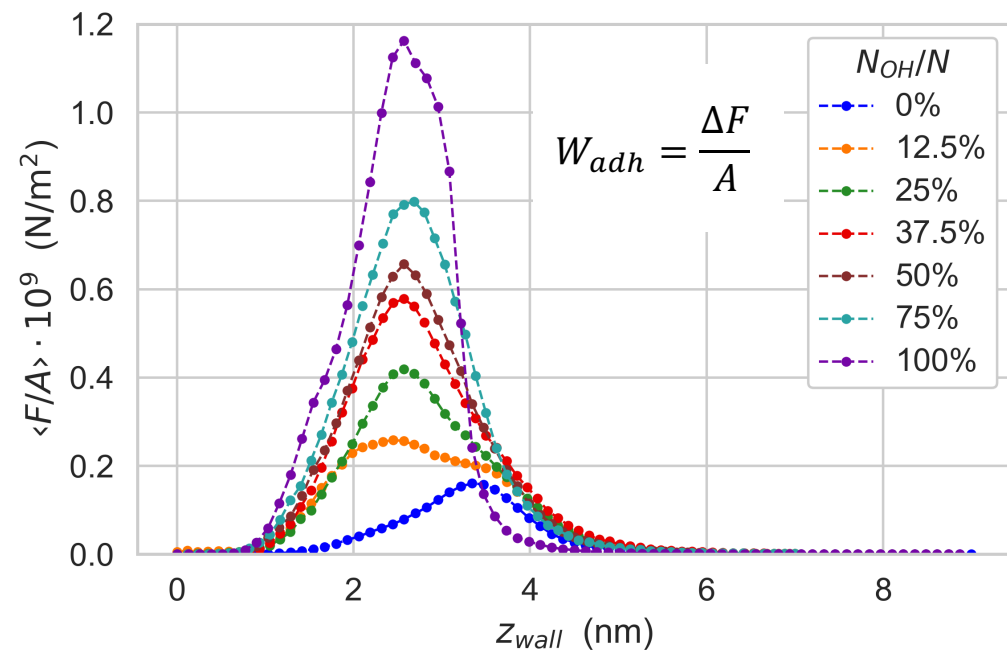
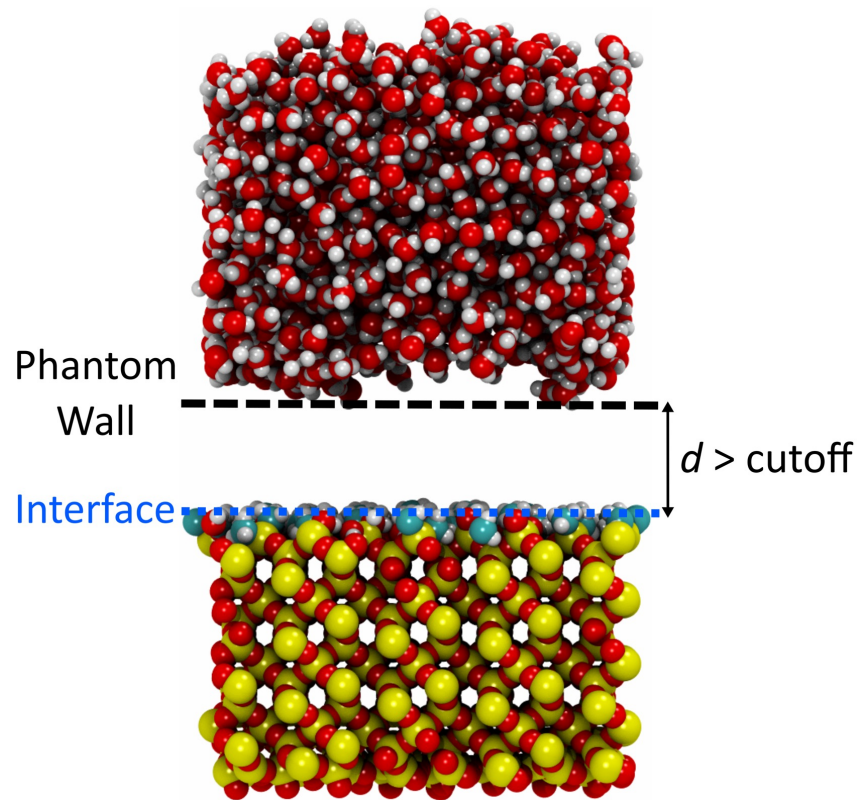
Functionalised silica interface



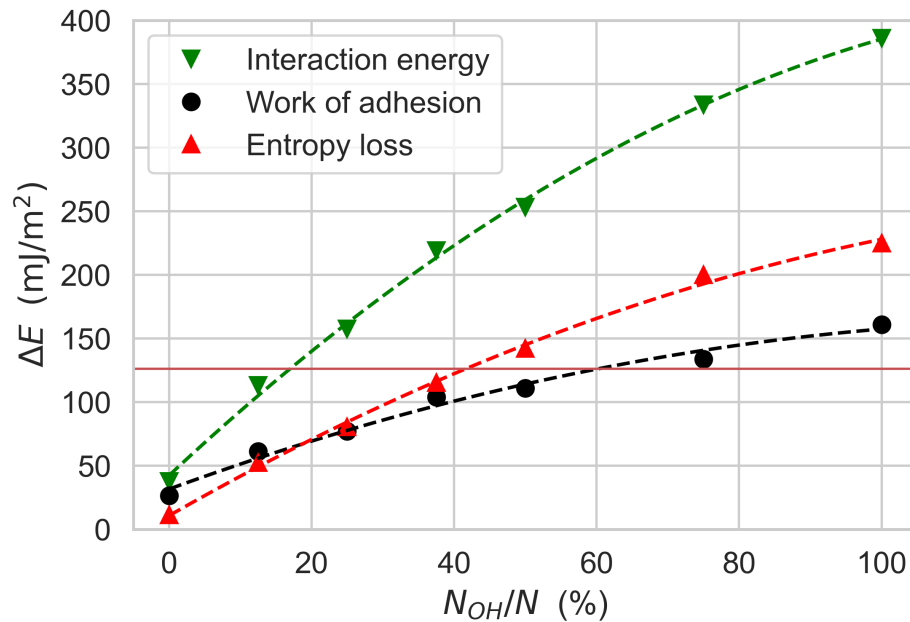
Functionalised silica interface



Work of adhesion



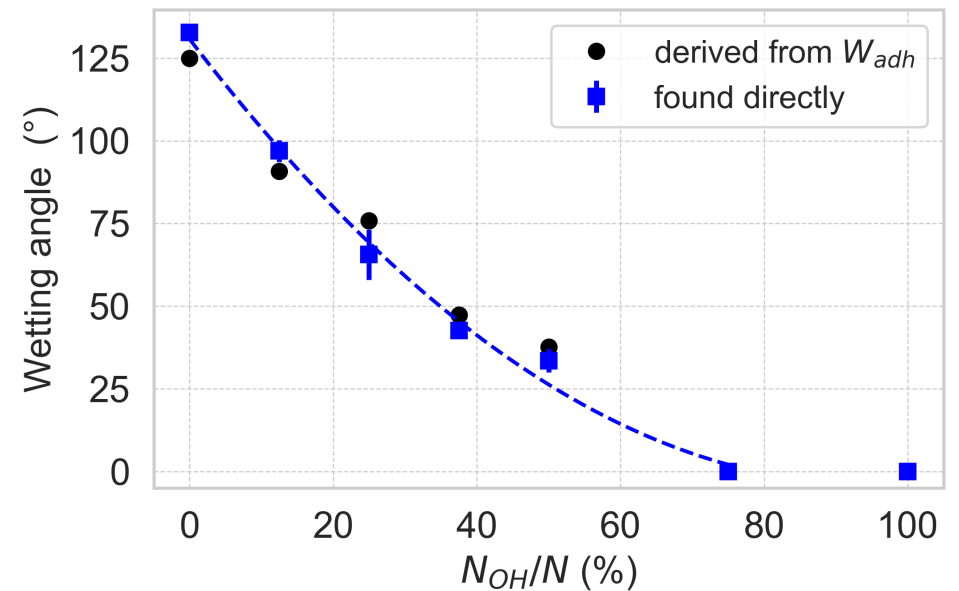
Work of adhesion vs contact angle



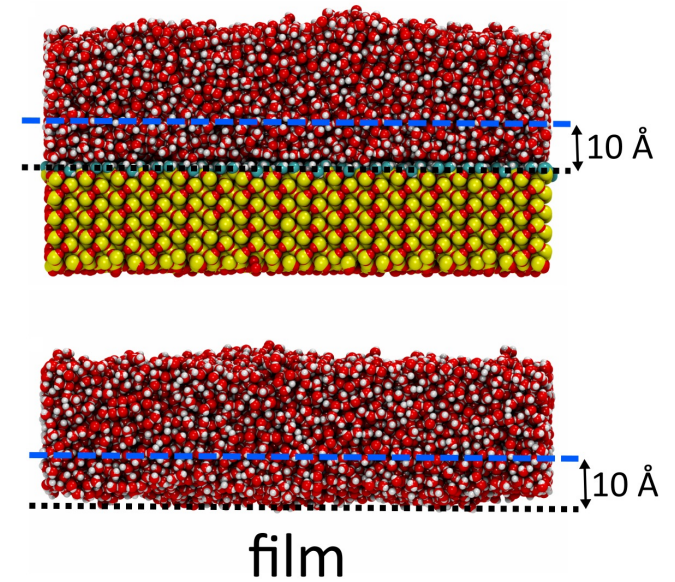
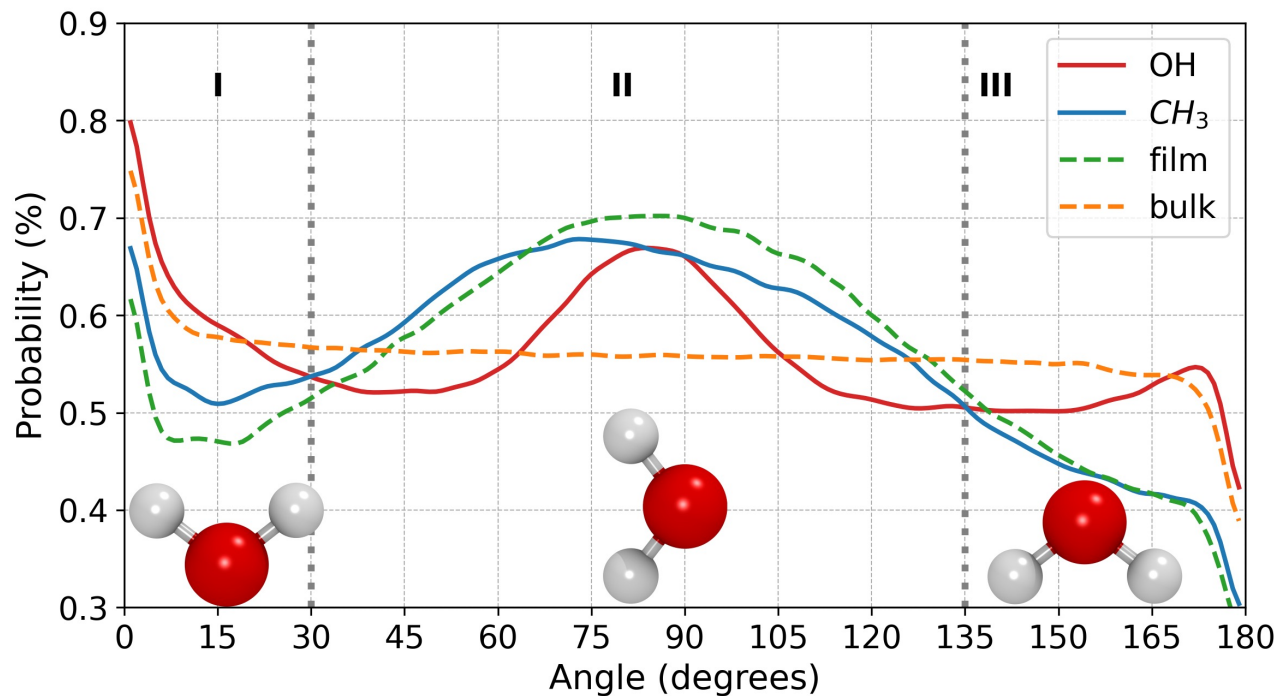
Young-Dupré equation

$$W_{adh} = \gamma_{lv}(1 + \cos \theta)$$

Work of adhesion Surface tension Wetting angle

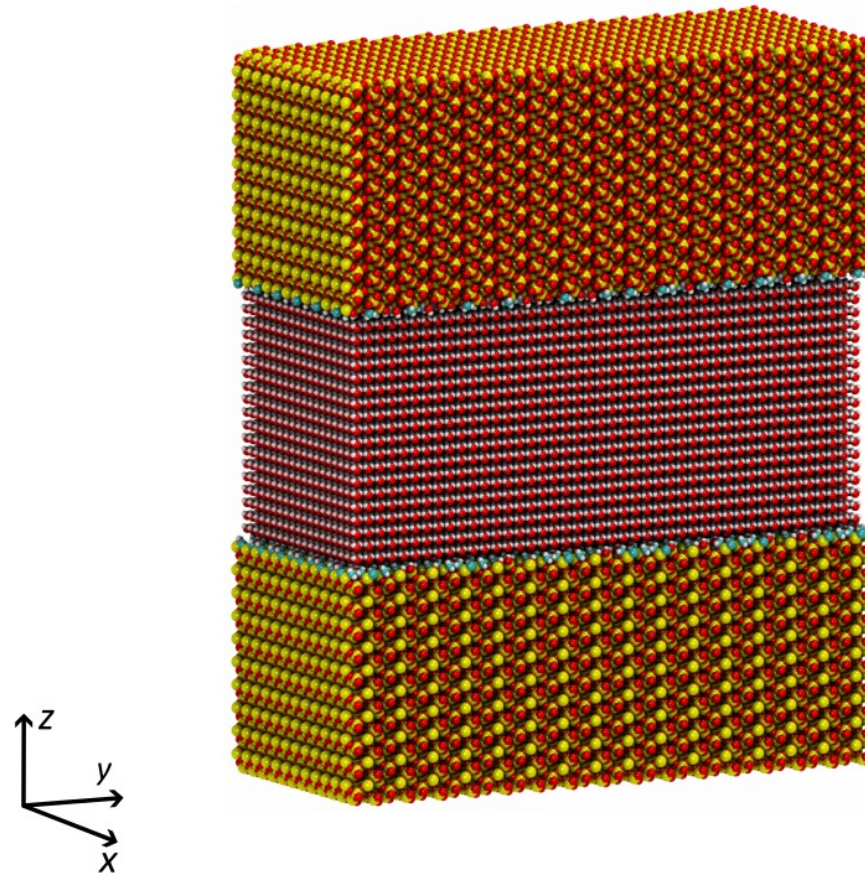


Probability of the water molecules' orientation

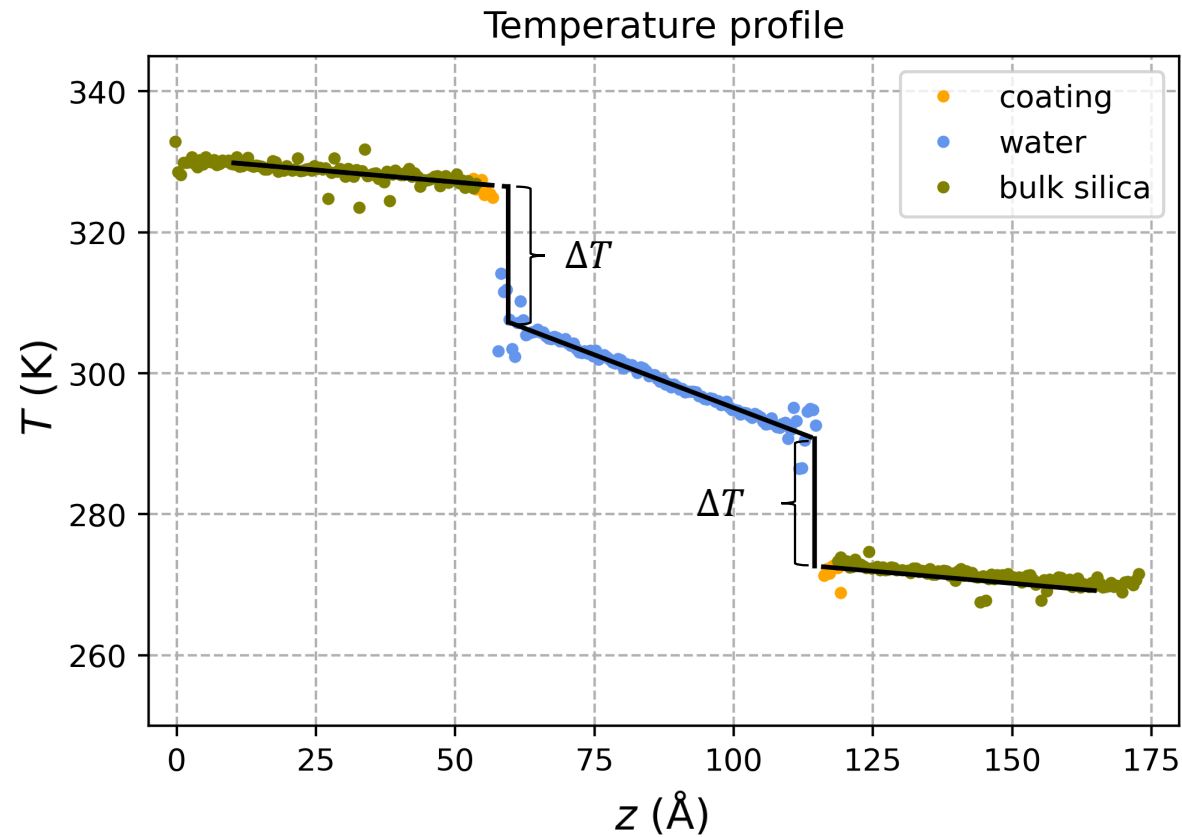


More perpendicular hydrogen bonds are formed for a hydrophilic (OH) surface, facilitating heat transfer

Thermal transport



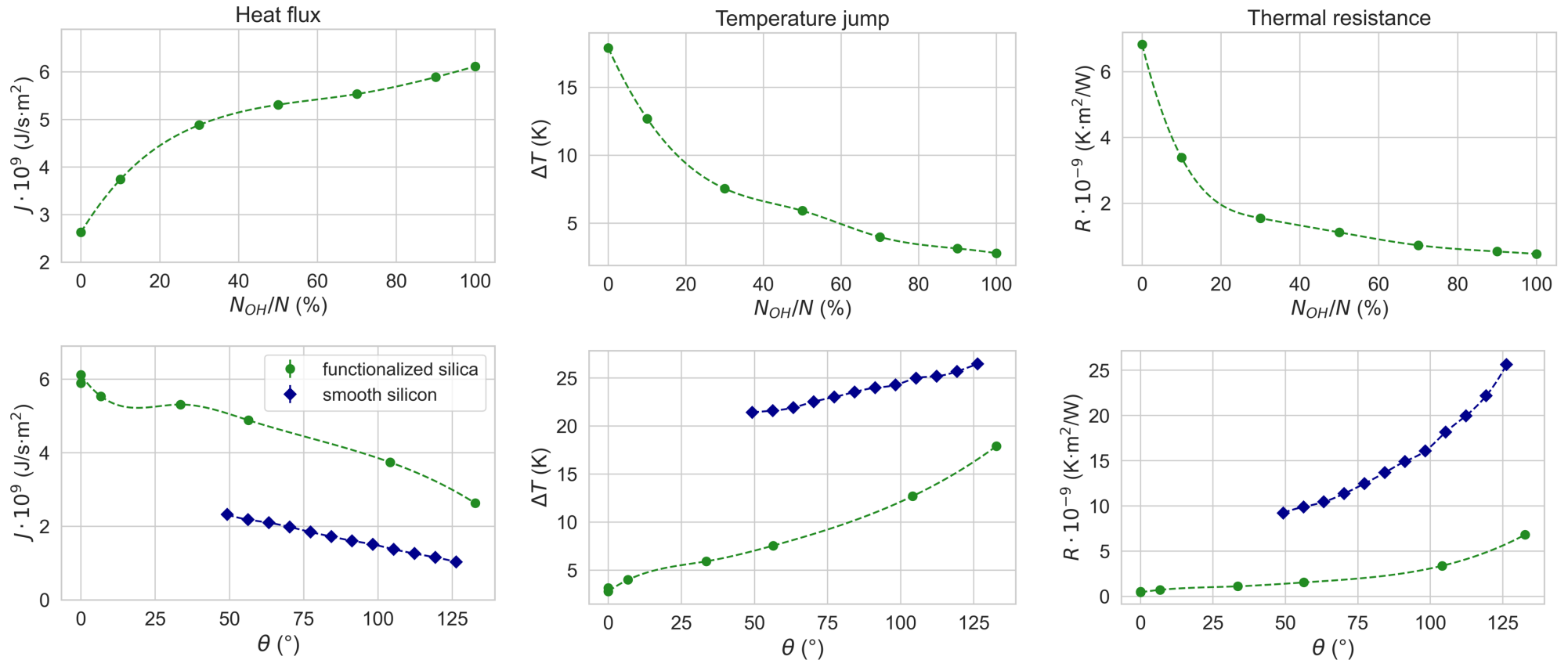
Interfacial thermal resistance



Thermal resistance:

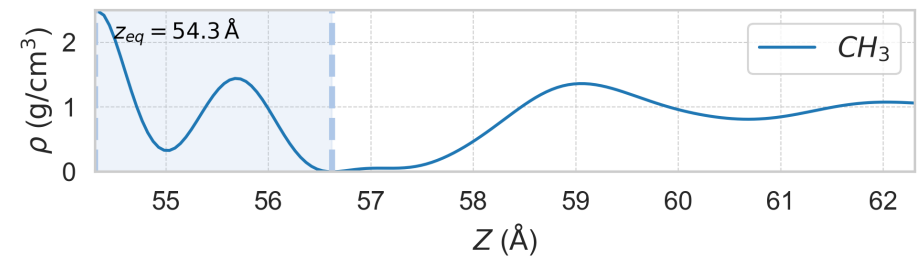
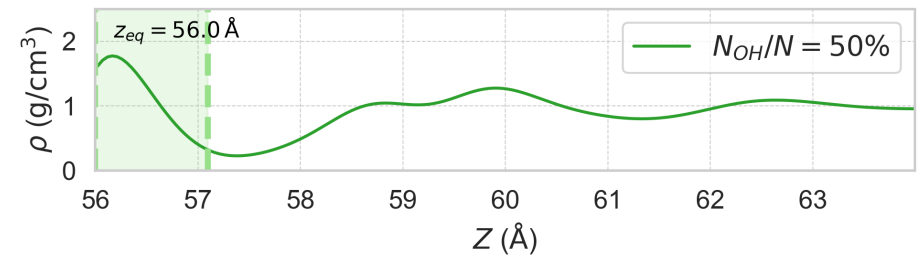
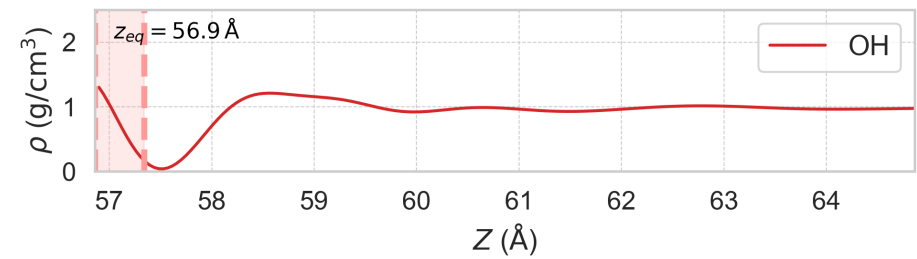
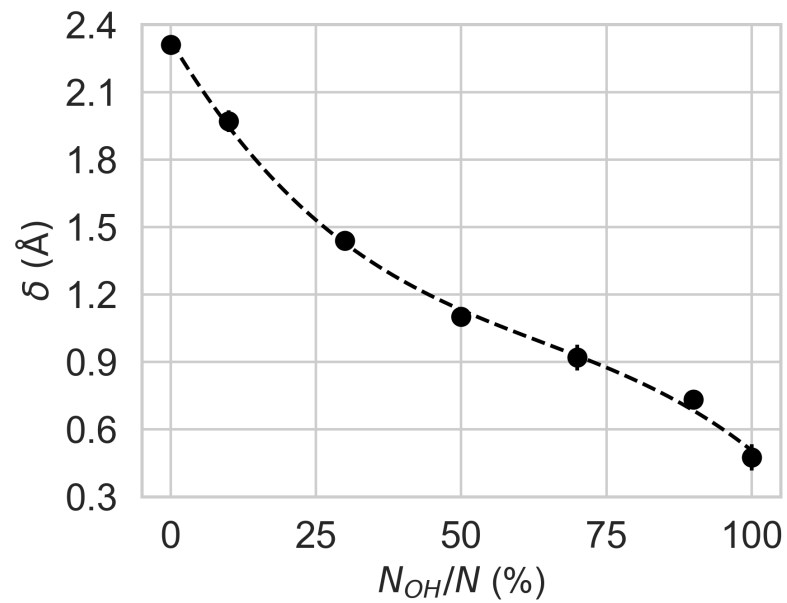
$$R = \frac{\Delta T}{J}$$

Interfacial thermal resistance

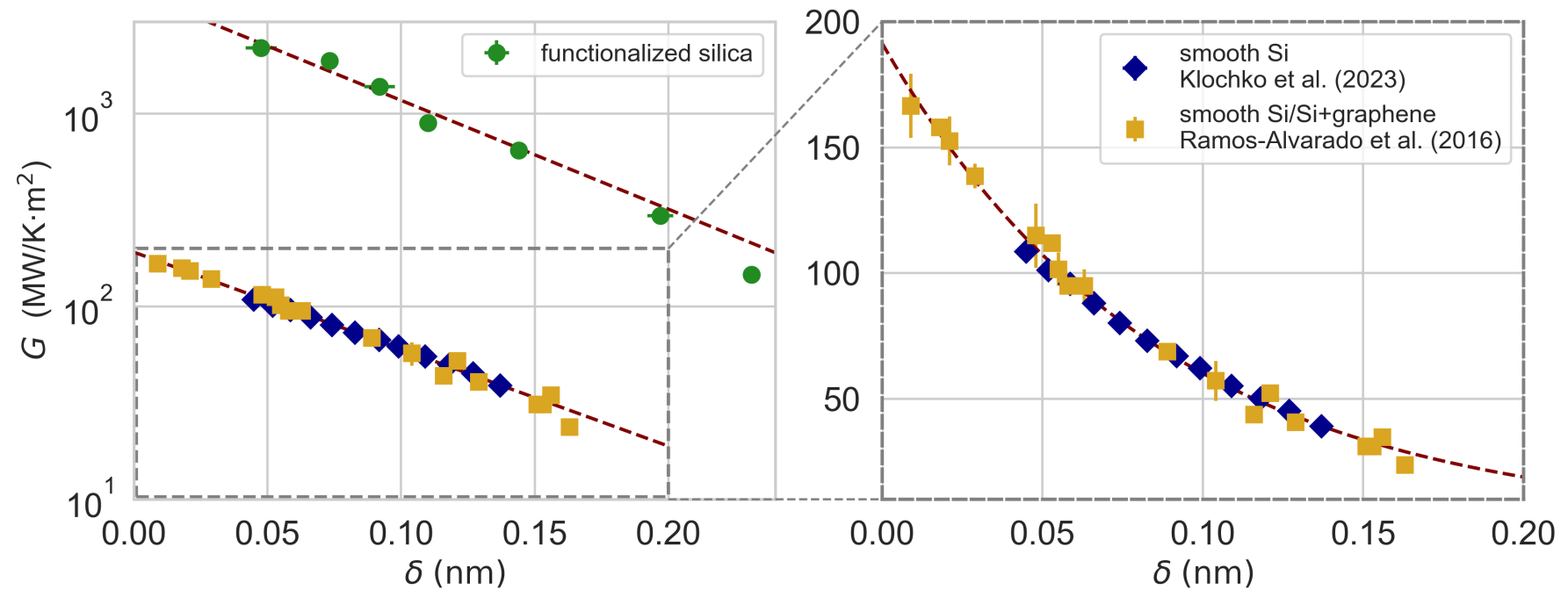


Interfacial thermal resistance

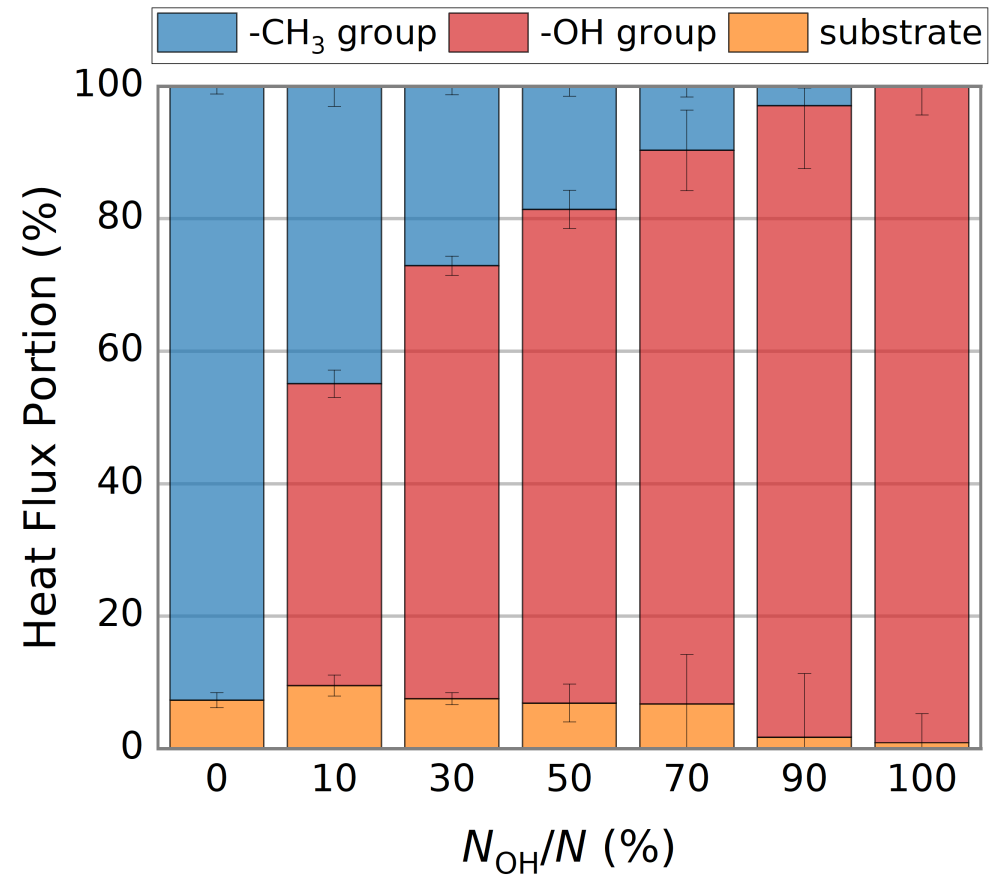
$$\delta = \int_0^{\infty} \left[1 - \frac{\rho_s(z)}{\rho_s^b} - \frac{\rho_l(z)}{\rho_l^b} \right] dz$$



Interfacial thermal resistance

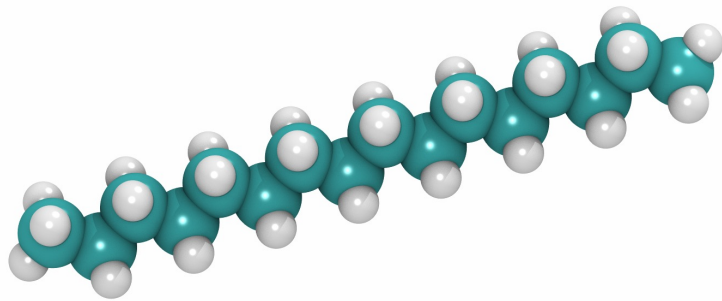


Heat flux decomposition

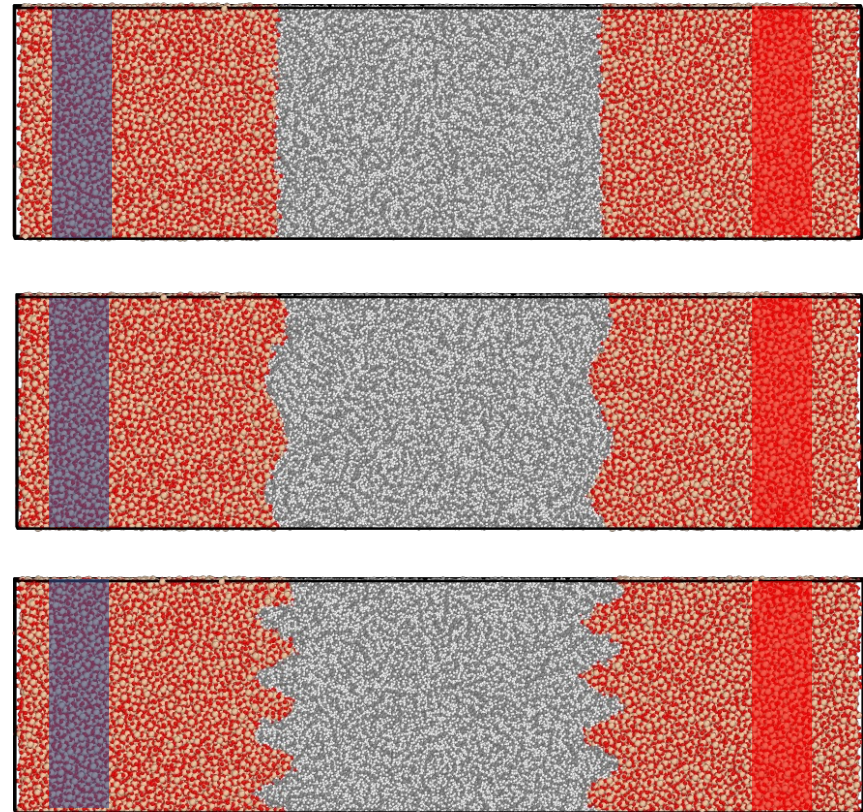


Thermal transport across a nanostructured interface

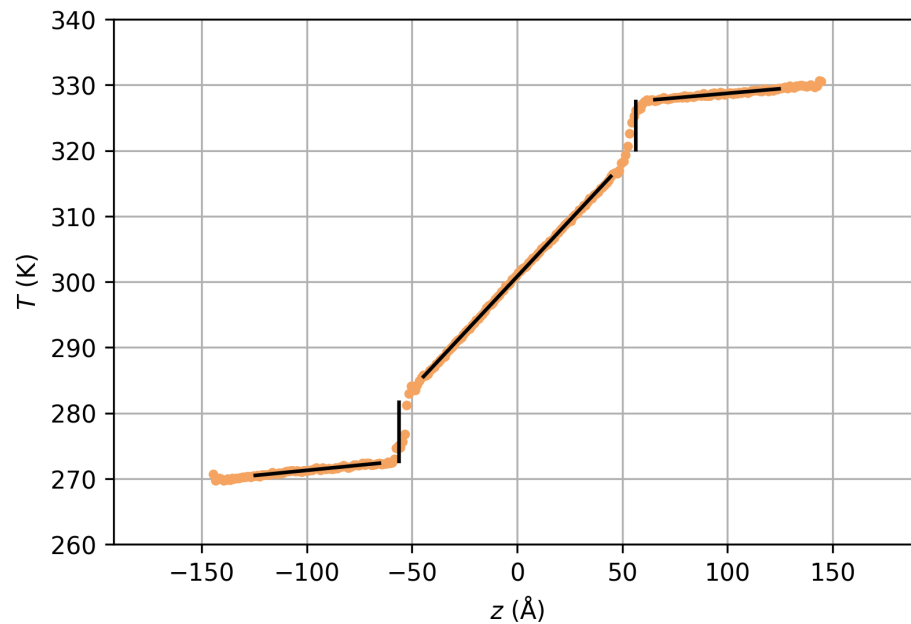
Thermal transport across amorphous silica (SiO₂) / hexadecane interface



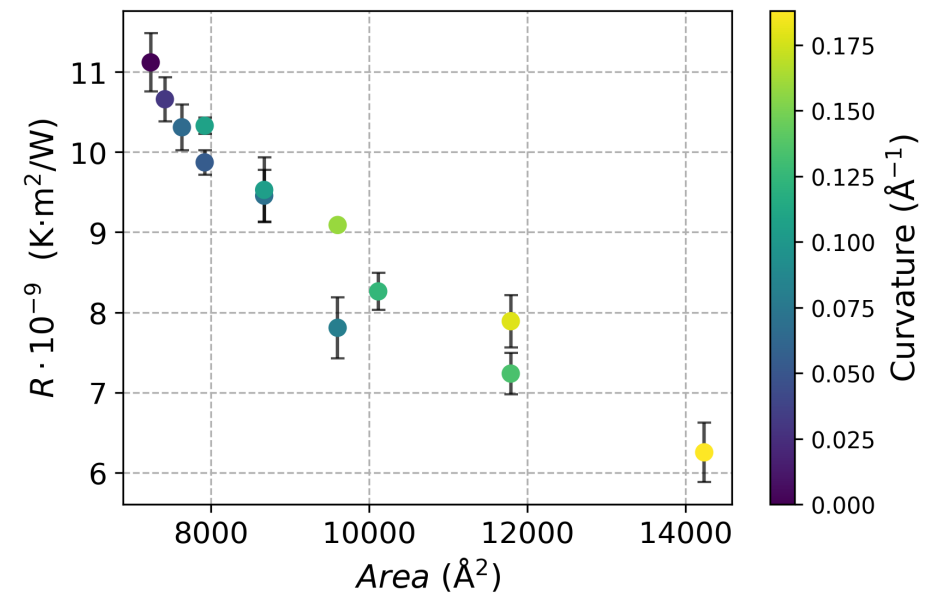
A molecule of hexadecane CH₃(CH₂)₁₄CH₃



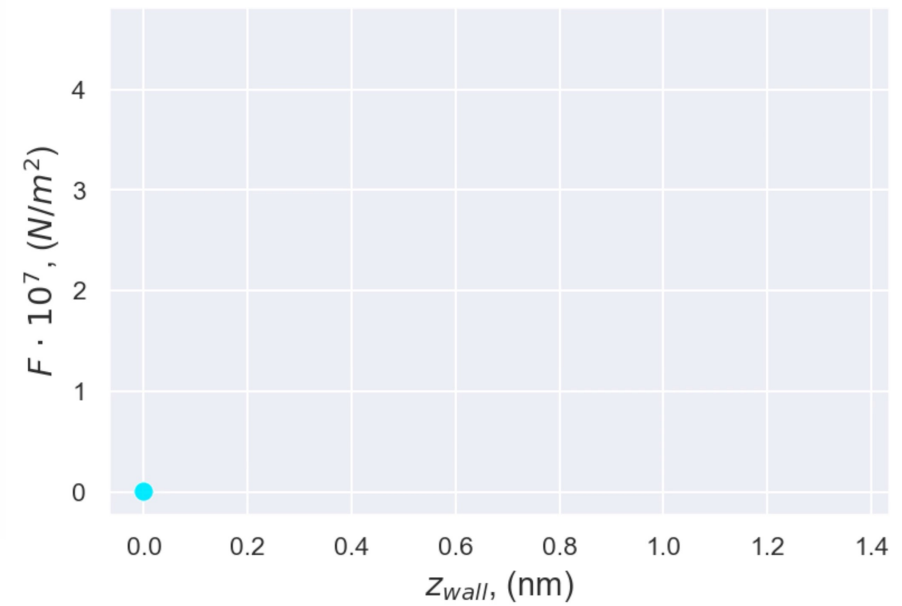
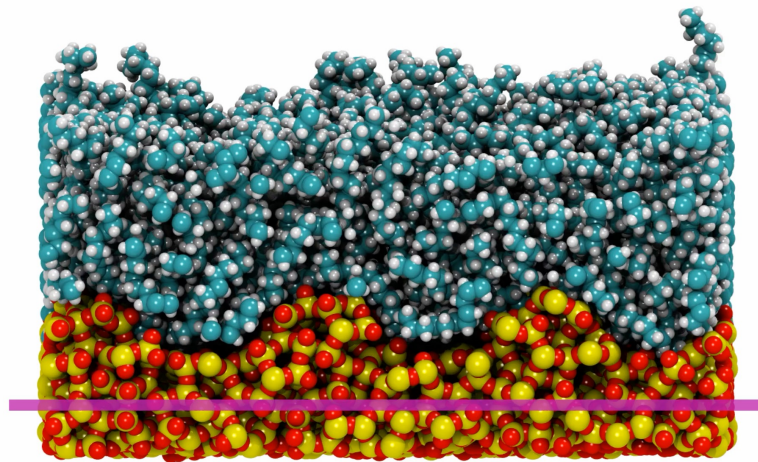
Thermal transport across a nanostructured interface



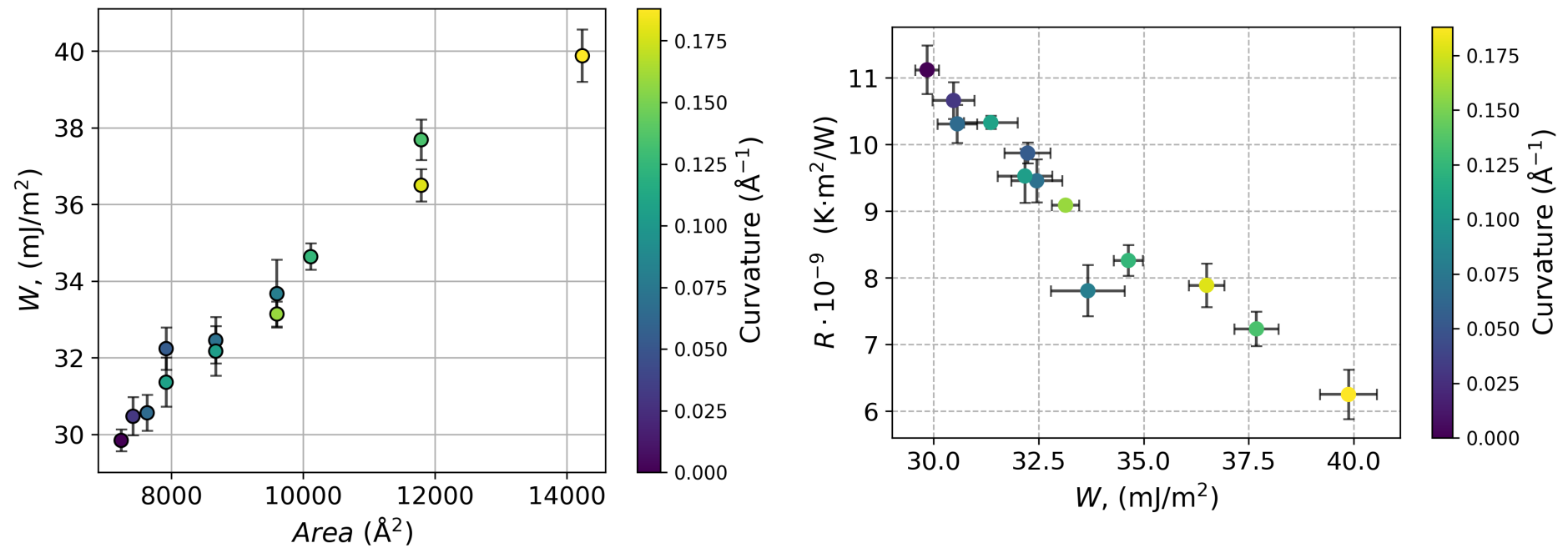
$$R = \frac{\Delta T}{J}$$



Work of adhesion



Work of adhesion



Conclusions

- We performed molecular dynamics simulations to investigate thermal transport across chemically functionalized and nanostructured solid–liquid interfaces.
- Functionalization of the silica surface with hydroxyl and methyl groups enabled control of the wetting angle over a wide range—from 0° to 130°. This, in turn, led to a variation in the interfacial thermal boundary resistance from approximately 0.5 to 7×10^{-9} K·m²/W.
- For nanostructured interfaces, we observed that the interfacial resistance decreases with increasing surface area. Furthermore, a clear dependence of this resistance on the average surface curvature was identified.